



Ultra-High Voltage Protection USB2 SPST Switch

Features

→ Differential Bi-Directional SPST Switch

→ Wide Input Voltage Range: 0-5.5V

→ Wide bandwidth: 1GHz

→ Ultra-low Con: 7pF

→ Ultra-low Ron: 5Ω (typ)

→ Low Propagation Delay, 0.25ns typ

→ Low Off-Isolation, -30dB@240MHz

→ Low Crosstalk: -35dB@240MHz,

→ Low Power Consumption: 35µA typical

→ Wide Supply Voltage 2.7-5.5V

→ Protection Feature

♦ Off-protection for current leakage in power-down mode

♦ All I/O pins are high voltage tolerance

C0+/C0- tolerance to 24V

• L0+/- tolerance to 6V

• V_{DD} tolerance to 6V

♦ Over-voltage protection when Vbus short to C0-/C0+ when device is power-on and enabled

→ ESD Protection on (C0+/-)

♦ IEC61000-4-2, 10kV

→ Wide Temperature Range: -40°C to 125°C

→ Automotive Grade 1 temperature range (-40°C to 125°C)

→ Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

→ Halogen and Antimony Free. "Green" Device (Note 3)

→ For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

https://www.diodes.com/quality/product-definitions/

- → Packaging (Pb-free & Green):
 - ♦ 10-contact, UQFN (ZUA), 1.5x2mm, 0.5mm(H), 0.6mm pitch

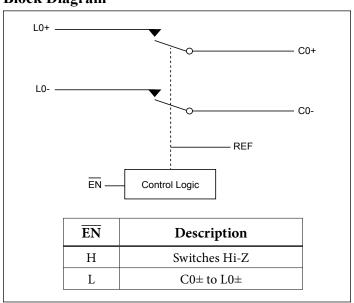
Description

The PI3USB4002AQ is a High voltage short and surge protector. C0+/C0- pins can tolerate voltages up to 24V. Over-voltage protection (OVP) is implemented at 4.75V to immediately switch off the channels when over-voltage condition is detected. PI3USB4002AQ can pass USB2.0 signal with bandwidth 1GHz to maintain signal integrity and eye diagram open.

Applications

→ Smart Phone, USB-C Application, Tablets, NB, PC

Block Diagram



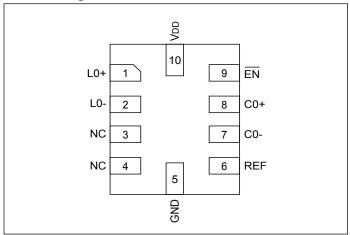
Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.





Pin Configuration



Pin Description

Pin#	Pin Name	Signal Type	Description		
8,	C0+,	1/0	2. 11/0 D (C.1		
7	C0-	I/O	Signal I/O, Port Side		
3, 4	NC	NC	No Connection		
1,	L0+,	110	Signal I/O, System Side		
2	L0-	I/O			
9	EN	I	$\overline{\rm EN}$ = 1, Power down is enabled. Please see Truth Table.		
6	REF	PWR	Reference pin, tie to GND through cap*		
5	GND	PWR	Power ground		
10	V_{DD}	PWR	Positive Supply Voltage		

^{*} The Cap on the REF pin required 1uF and 25V tolerance

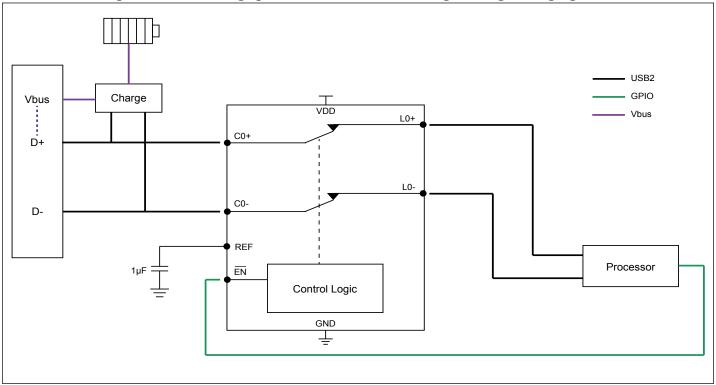
Truth Table

Function	EN
C0+/- to L0+/-	L
All Switches Hi-Z	Н





PI3USB4002AQ provide overvoltage protection for D+/- when high voltage charging



Note:

The capacitor connected to REF pin should have rated voltage higher than maximum voltage applied to C0+/- pins; the max rating of device on C0+/- is 24V, customer can select lower voltage capacitor if system required lower voltage tolerance on C0+/-; capacitance of 1uF.

- 1. The 1uF capacitor recommend to be placed to the REF and GND pin of the device as close as possible
- 2. The decoupling capacitor at the VDD recommend to be placed to the device as close as possible.
- 3. Keep the trace between connector and device as long as possible; if needs inductor between device and connector, it recommend to be placed to the USB connector as close as possible and leaving some trace line between the device and the inductor would help some for the ESD performance.





Maximum Ratings

(Above which useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to +150°C
Supply Voltage (VDD) to Ground Potential0.3V to +6V
Channel Input/Output Voltage (L0+/-)0.3V to +6V
Channel Input/Output Voltage (C0+/-)0.3V to +24V
Reference Pin Voltage (REF) to Ground Potential0.3V to +24V
Control Pins Input Voltage (EN)0.3V to +6V
ESD (All Pins)2KV (HBM) and 1KV (CDM)
Channel Input/Output Current (L0/C0)±25mA

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Description	Test Conditions	Min.	Тур.	Max.	Units
V_{DD}	Power Supply		2.7	3.3	5.5	V
V _{I/O}	Analog Voltage Range		0		5.5	V
$V_{\rm I}$	Voltage Range for Control Pins		0		5.5	V
I_{DD}	Current Consumption in Normal Operation	$V_{DD} = 3.3V$, $V_{IO} = 0V$, $\overline{EN} = Low$		35	45	μA
I_{DDQ}	Chip Disabled Current Consumption	$V_{DD} = 3.3V$, $V_{IO} = 0V$, $\overline{EN} = High$		1	2	μA
T_{A}	Operating Temperature Range		-40		125	°C

DC Electrical Characteristics for Switching over Operating Range

 $(T_A = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}, \text{ Typical values are at V}_{DD} = 3.3\text{V}, T_A = 25^{\circ}\text{C}, \overline{EN} = 0\text{V}, REF = NC \text{ (unless otherwise noted)})$

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units
Control Pins – EN					·	
V _{IH} - cntrl signals	Input HIGH Voltage for EN	$V_{\rm DD} = 2.7-5.5 V$	1.2			V
V _{IL} - cntrl signals	Input LOW Voltage for EN	$V_{\rm DD} = 2.7-5.5 V$			0.6	V
I _{IH}	Input HIGH Current for EN	$V_{\rm I} = 5.5 \rm V$	-1		1	μA
I _{IL}	Input LOW Current for EN	$V_{I} = 0V$	-1		1	μA
High Speed IO – L	0/C0					
V _{OVP}	CO± OVP trigger voltage		4.6	4.75	5.0	V
Ron	ON resistance	$V_{I/O} = 0V, 0.4V, I_{on} = -8mA$		5	10	Ω
Δ Ron	On resistance between + and - channel	$V_{I/O} = 0V, 0.4V, I_{on} = -8mA$		0.5	1	Ω
Ron_Flat	ON resistance flatness	$V_{I/O} = 0V, 0.4V, I_{on} = -8mA$		0.2	0.5	Ω
I _{off}	CO± Power-off leakage	$V_{DD} = 0V, V_{CO+/-} = 0 - 3.6V$	-1		1	μA
I_{OC}	Channel off leakage current	$\overline{\rm EN} = { m V_{DD}} = 3.3 { m V, V_{I/O}} = 0 - 3.6 { m V}$	-1		1	μA
I _{ON}	Channel on leakage current	$\overline{\rm EN}$ = 0V, V _{DD} = 3.3V, V _{I/O} = 0 - 3.6V	-1		1	μΑ
I _{OVP}	Leakage current on C0+/C0- in OVP mode	$\overline{\overline{EN}}$ = 0V, V _{DD} = 3.3V, V _{C0+} or V _{C0-} = 20V			1	mA
Z _{ON_GND}	On state impedance to GND	$\overline{\rm EN} = 0 { m V}, { m V}_{ m DD} = 3.3 { m V}, { m V}_{ m I/O} = 0 - 3.6 { m V}$	3.5	7		ΜΩ





Dynamic Electrical Characteristics

 $(T_A = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}, \text{ Typical values are at V}_{DD} = 3.3\text{V}, T_A = 25^{\circ}\text{C}, \text{ (unless otherwise noted))}$

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units		
Control Pins – F	Control Pins - EN							
C _I	Input Capacitance	f=1MHz		5		pF		
High Speed IO -	High Speed IO – L0/C0							
Con	ON Capacitance	f=1MHz		7		pF		
Coff	OFF Capacitance	f=1MHz		9		pF		
I_{L}	Insertion Loss	f=240MHz		-0.5		dB		
R_{L}	Return Loss	f=240MHz		-15		dB		
O _{IRR}	OFF Isolation	f=240MHz		-30		dB		
X _{TALK}	Crosstalk	f=240MHz		-35		dB		
BW	-3dB Bandwidth			1		GHz		

Switching Characteristics

 $(T_A = -40^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}, \text{ Typical values are at V}_{DD} = 3.3\text{V}, T_A = 25^{\circ}\text{C}, \text{ (unless otherwise noted))}$

Parameter	Description	Test Conditions	Min.	Тур.	Max.	Units
t _{OVP}	OVP Response Time ⁽¹⁾	$R_{L0}=600\Omega$, time from the voltage on $C0\pm=4{\sim}6V$ to the voltage on $L_0\pm=4.75V$		0.5	1	μs
t _{Pd}	Propagation Delay			250		ps
t _{b-b}	Bit-to-bit Skew Within the Same Dif- ferential Pair ⁽¹⁾	See Test Circuit for Electrical Characteristics		8	20	ps
t _{on}	Device Enable Time			100		μs
t _{off}	Device Disable Time			50		ns

Note:

1. Guaranteed by design.





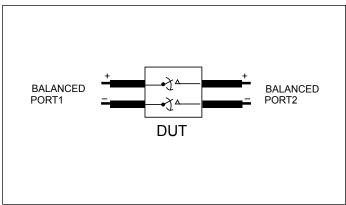


Fig 1. Differential Insertion Loss Setup

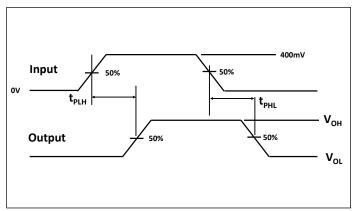


Fig 2. Propagation Delay

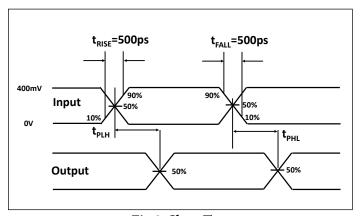
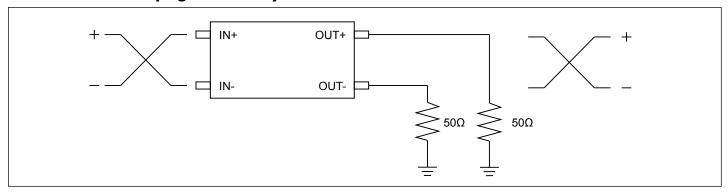


Fig 3. Skew Test





Test Circuit for Propagation Delay



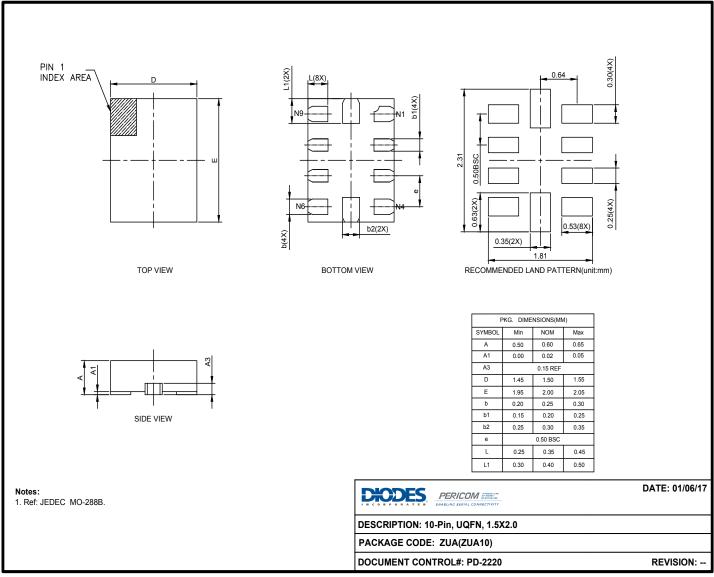
Part Marking

Top mark not available at this time. To obtain advance information regarding the top mark, please contact your local sales representative.





Packaging Mechanical: 10-UQFN (ZUA)



17-0002

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Package Code	Package Description
PI3USB4002AQ1ZUAEX ZUA		10-Pin, 1.5 x 2.0 (UQFN)

Notes:

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- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Q = Automotive Compliant
- 5. 1 = AEC-Q100 Grade Level
- 6. E = Pb-free and Green
- 7. X suffix = Tape/Reel





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